NCE P-Channel Enhancement Mode Power MOSFET

Description

The NCE60P50G uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge .This device is well suited for high current load applications.

Application

- High side switch for full bridge converter
- DC/DC converter for LCD display

100% UIS TESTED!

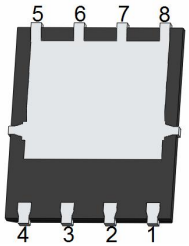
100% ΔVds TESTED!

General Features

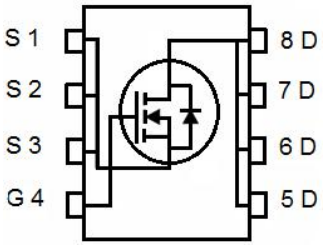
- V_{DS} =-60V,I_D =-50A
  $R_{DS(ON)}$=23mΩ (typical) @ V_{GS}=-10V
- High density cell design for ultra low Rdson
- Very low on-resistance $R_{DS(on)}$
- Good stability and uniformity with high E_{AS}
- 150 °C operating temperature
- Pb-free lead plating

DFN 5X6

Top View



Bottom View



Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
NCE60P50G	NCE60P50G	DFN5X6-8L	-	-	-

Absolute Maximum Ratings (T_C=25℃unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	-60	V
Gate-Source Voltage	V_{GS}	±20	V
Drain Current-Continuous	I_D	-50	A
Drain Current-Continuous(T_C=100℃)	I_D (100℃)	-35	A
Pulsed Drain Current(Note 1)	I_{DM}	-200	A
Maximum Power Dissipation	P_D	100	W
Derating factor		0.8	W/℃
Single pulse avalanche energy (Note 5)	E_{AS}	273	mJ
Operating Junction and Storage Temperature Range	T_J,T_{STG}	-55 To 150	℃

Thermal Characteristic

Thermal Resistance, Junction-to-Case(Note 2)	$R_{\theta JC}$	1.25	℃/W

Electrical Characteristics (T_C=25℃unless otherwise noted)

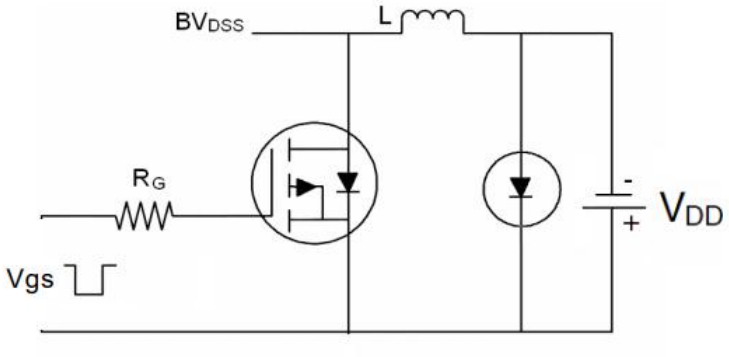
Parameter	Symbol	Condition	Min	Typ	Max	Unit
Off Characteristics						
Drain-Source Breakdown Voltage	BV_{DSS}	V_{GS}=0V I_D=-250μA	-60	-	-	V
Zero Gate Voltage Drain Current	I_{DSS}	V_{DS}=-60V,V_{GS}=0V	-	-	-1	μA
Gate-Body Leakage Current	I_{GSS}	V_{GS}=±20V,V_{DS}=0V	-	-	±100	nA
On Characteristics (Note 3)						
Gate Threshold Voltage	$V_{GS(th)}$	V_{DS}=V_{GS},I_D=-250μA	-2	-2.6	-3.5	V
Drain-Source On-State Resistance	$R_{DS(ON)}$	V_{GS}=-10V, I_D=-20A	-	23	28	mΩ
Forward Transconductance	g_{FS}	V_{DS}=-5V,I_D=-20A	-	25	-	S
Dynamic Characteristics (Note4)						
Input Capacitance	C_{lss}	V_{DS}=-30V,V_{GS}=0V, F=1.0MHz	-	3016.8	-	PF
Output Capacitance	C_{oss}		-	180	-	PF
Reverse Transfer Capacitance	C_{rss}		-	126	-	PF
Switching Characteristics (Note 4)						
Turn-on Delay Time	$t_{d(on)}$	V_{DD}=-30V, R_L=1.5Ω, V_{GS}=-10V,R_G=3Ω	-	12	-	nS
Turn-on Rise Time	t_r		-	15	-	nS
Turn-Off Delay Time	$t_{d(off)}$		-	38	-	nS
Turn-Off Fall Time	t_f		-	15	-	nS
Total Gate Charge	Q_g	V_{DS}=-30,I_D=-20A, V_{GS}=-10V	-	49.8		nC
Gate-Source Charge	Q_{gs}		-	10.6		nC
Gate-Drain Charge	Q_{gd}		-	13.6		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V_{SD}	V_{GS}=0V,I_S=-20A	-		-1.2	V
Diode Forward Current (Note 2)	I_S		-	-	-50	A
Reverse Recovery Time	t_{rr}	TJ = 25°C, IF =- 20A di/dt = -100A/μs(Note3)	-	47		nS
Reverse Recovery Charge	Qrr		-	53		nC

Notes:

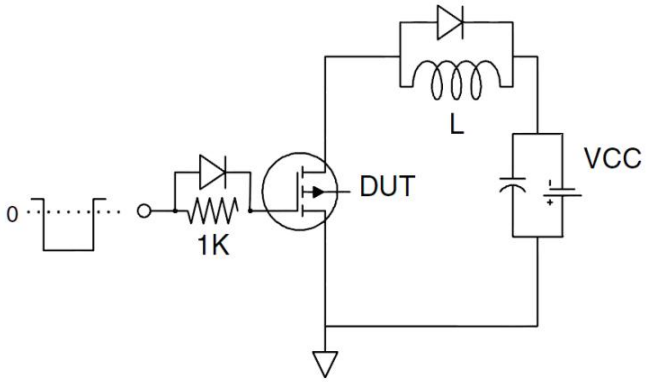
1. Repetitive Rating: Pulse width limited by maximum junction temperature.
2. Surface Mounted on FR4 Board, t ≤ 10 sec.
3. Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2%.
4. Guaranteed by design, not subject to production
5. E_{AS} condition: Tj=25℃,V_{DD}=-20V,V_G=-10V,L=0.5mH,Rg=25Ω

Test Circuit

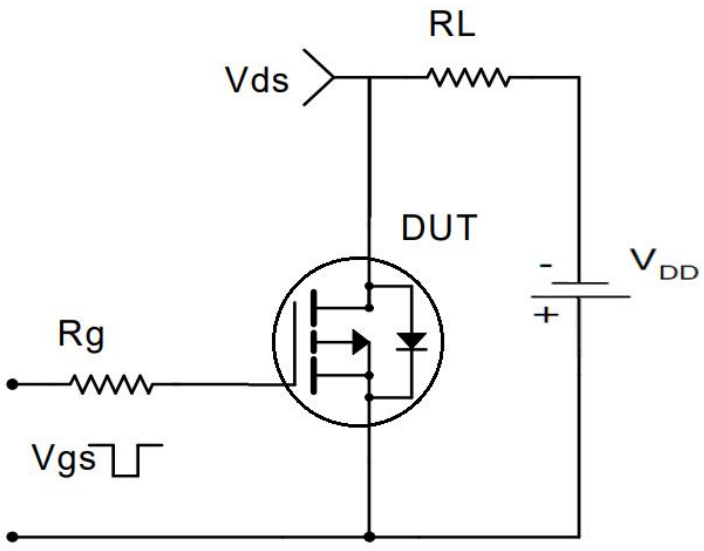
1) E_{AS} Test Circuit



2) Gate Charge Test Circuit



3) Switch Time Test Circuit



Typical Electrical and Thermal Characteristics (Curves)

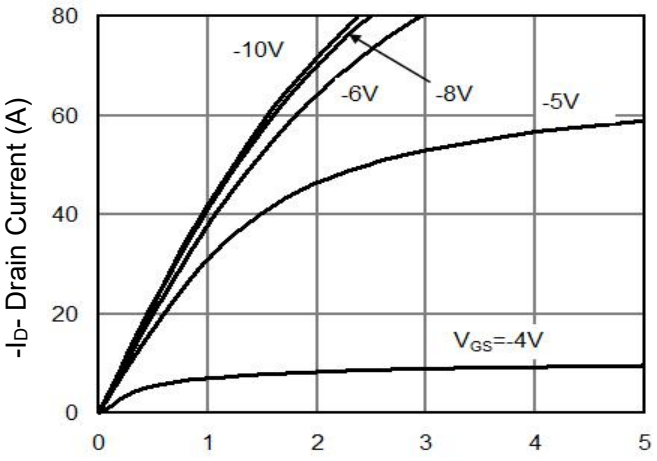


Figure 1 Output Characteristics

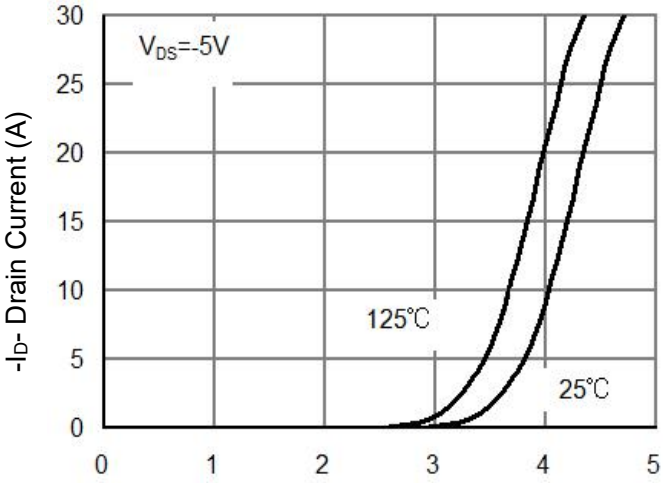


Figure 2 Transfer Characteristics

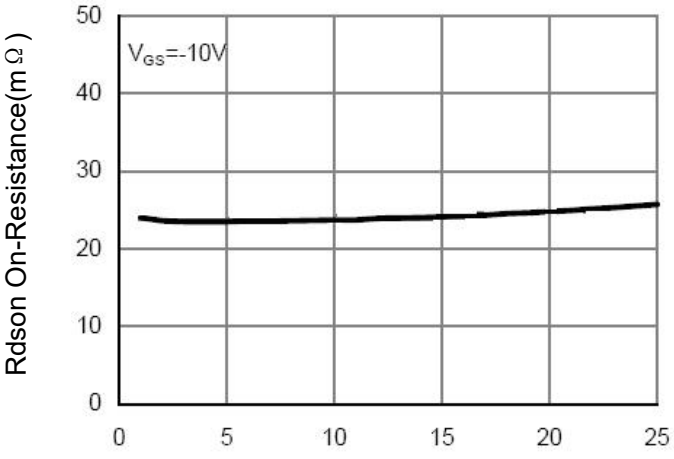


Figure 3 Rdson- Drain Current

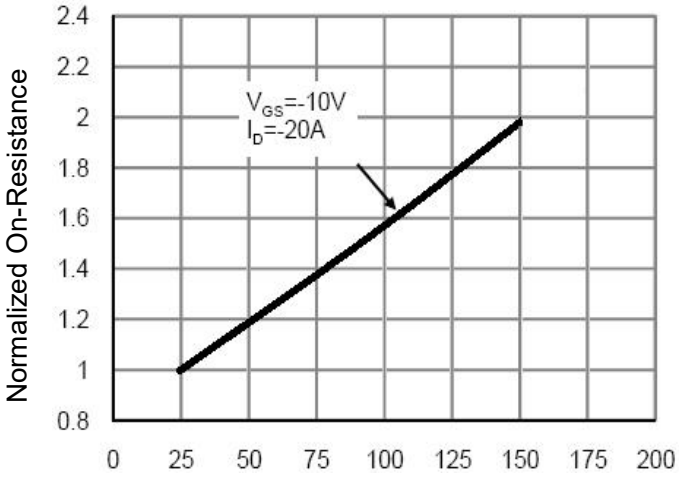


Figure 4 Rdson-Junction Temperature

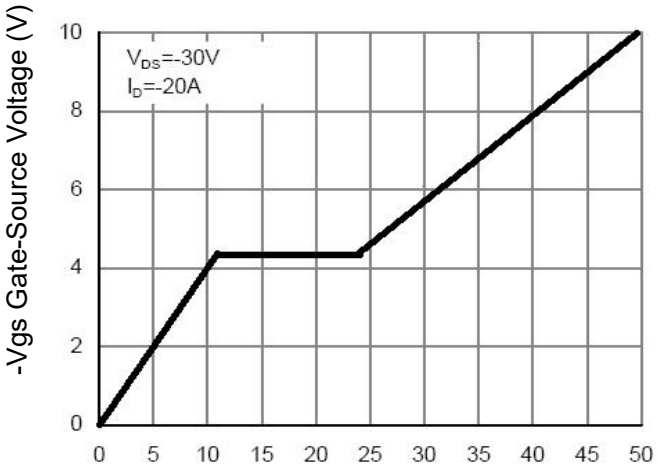


Figure 5 Gate Charge

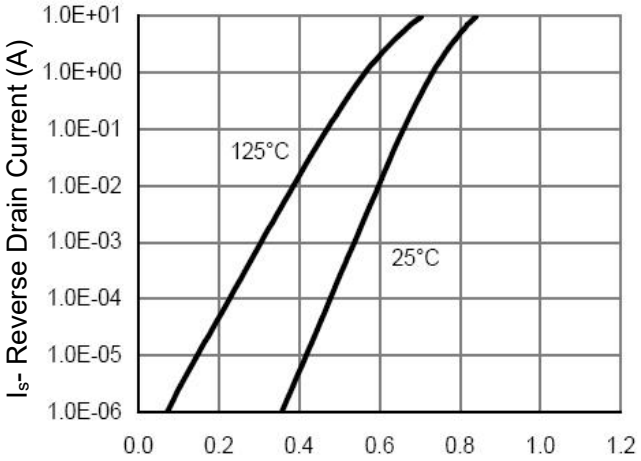


Figure 6 Source- Drain Diode Forward

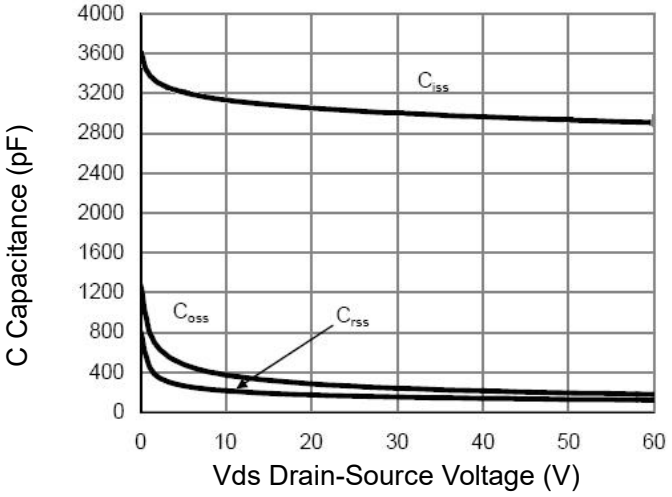
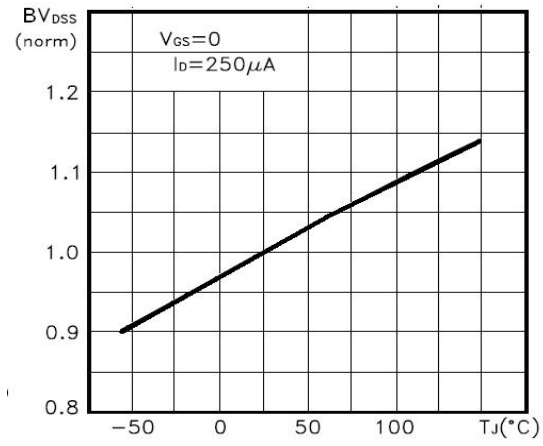
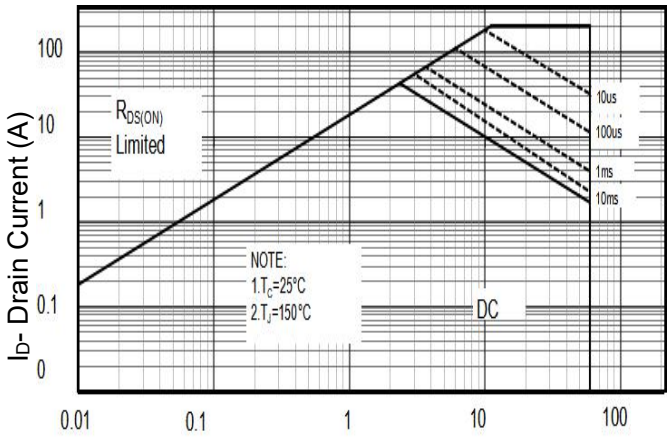


Figure 7 Capacitance vs Vds



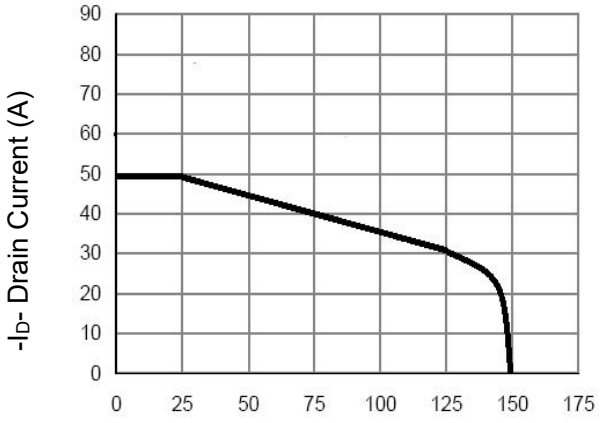
TJ-Junction Temperature(℃)

Figure 9 BV_{DSS} vs Junction Temperature



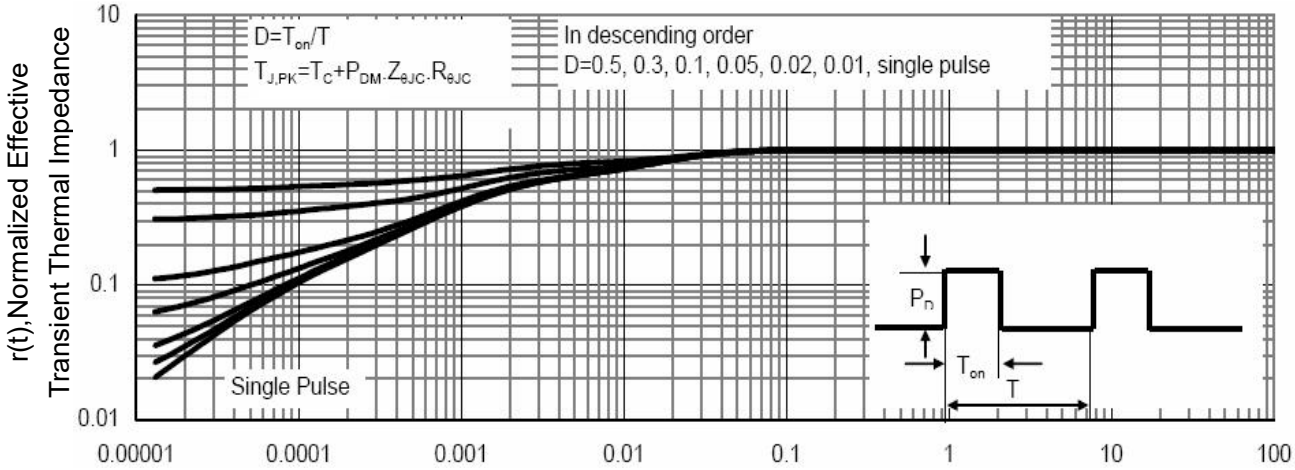
-Vds Drain-Source Voltage (V)

Figure 8 Safe Operation Area



TJ-Junction Temperature(℃)

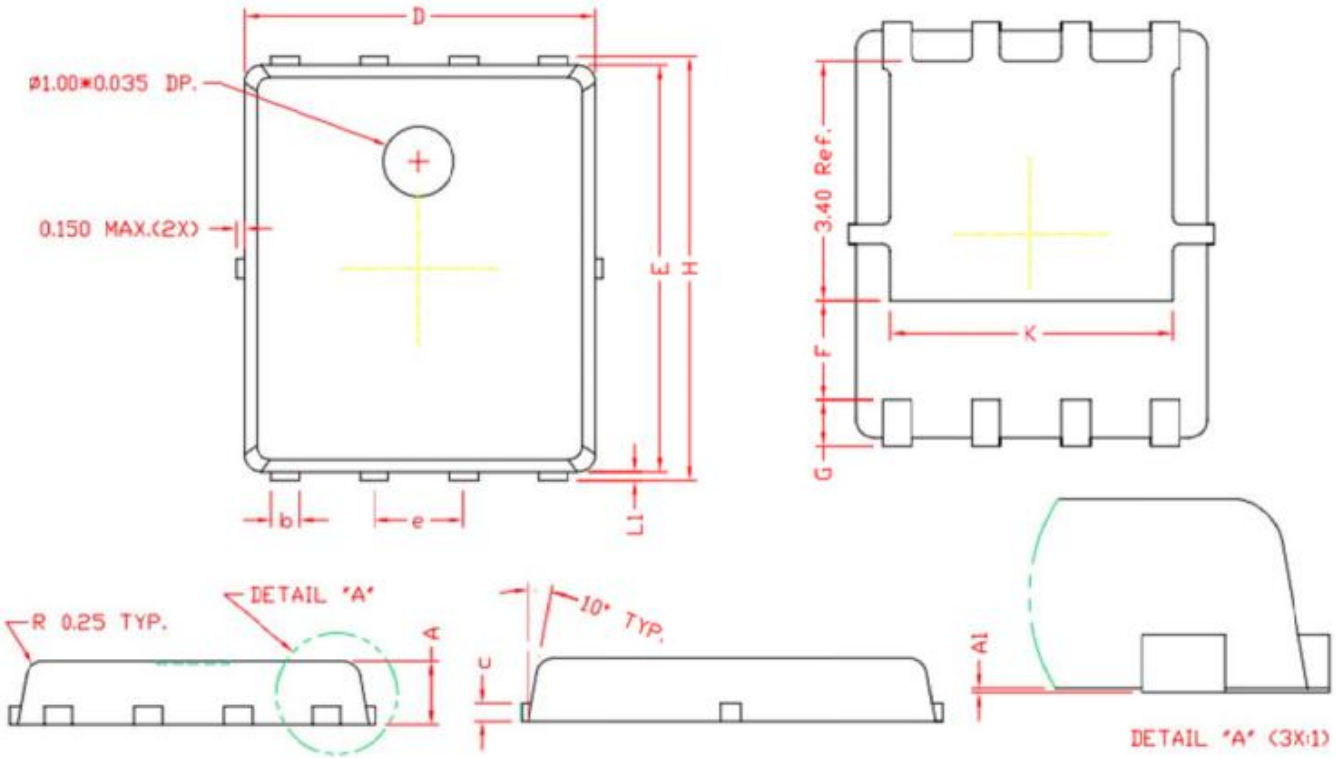
Figure 10 ID Current De-rating



Square Wave Pluse Duration(sec)

Figure 11 Normalized Maximum Transient Thermal Impedance

DFN5X6-8L Package Information



COMMON DIMENSIONS

(UNITS OF MEASURE=MILLIMETER)

SYMBOL	MIN	NOM	MAX
A	0.80	0.90	1.00
A1	0.00	0.03	0.05
b	0.35	0.42	0.49
c		0.254 REF.	
D	4.90	5.00	5.10
F		1.40 REF.	
E	5.70	5.80	5.90
e		1.27 BSC.	
H	5.95	6.08	6.20
L1	0.10	0.14	0.18
G		0.60 REF.	
K		4.00 REF.	

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